









SN74AC573 SCAS542H - OCTOBER 1995 - REVISED FEBRUARY 2024

SN74AC573 Octal D-type Transparent Latches with 3-State Outputs

1 Features

- Operation of 2V to 6V V _{CC}
- Inputs accept voltages to 6V
- Maximum t_{pd} of 9ns at 5V
- 3-State outputs drive bus lines directly

2 Applications

- **Buffer registers**
- Bidirectional bus drivers
- Working registers

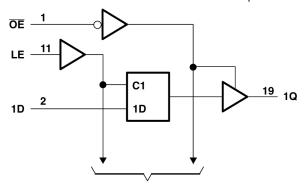
3 Description

These 8-bit latches feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. The devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE(2)	BODY SIZE(3)
	RKS (VQFN, 20)	4.5 mm × 2.5 mm	4.5mm × 2.5mm
	DB (SSOP, 20)	7.2 mm × 7.8 mm	7.2mm x 5.30mm
	DGV (TVSOP, 20)	5 mm × 6.4 mm	5mm × 4.4mm
SN74AC573	DW (SOIC, 20)	12.8 mm × 10.3 mm	12.80mm x 7.50mm
	NS (SOP, 20)	12.6 mm × 7.8 mm	12.6mm x 5.3mm
	N (PDIP, 20)	24.33 mm × 9.4 mm	24.33mm x 6.35mm
	PW (TSSOP, 20)	6.5 mm × 6.4 mm	6.50mm x 4.40mm

- For more information, see Section 11. (1)
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



To Seven Other Channels

Logic Diagram (Positive Logic)

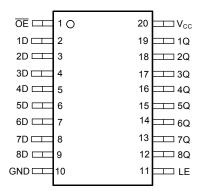


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4 Pin Configuration and Functions



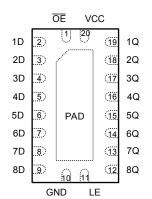


Figure 4-1. DB, DGV, DW, NS, N, or PW Packages, 20-Pin SSOP, TVSOP, SOIC, SOP, PDIP, or TSSOP (Top View)

Figure 4-2. RKS Package, 20-Pin VQFN (Top View)

Table 4-1. Pin Functions

	PIN	TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.	ITPE(''	DESCRIPTION
ŌĒ	1	I	Output enable
1D	2	I	1D input
2D	3	I	2D input
3D	4	ı	3D input
4D	5	I	4D input
5D	6	ı	5D input
6D	7	I	6D input
7D	8	I	7D input
8D	9	ı	8D input
GND	10	_	Ground
LE	11	I	Latch enable input
8Q	12	0	8Q output
7Q	13	0	7Q output
6Q	14	0	6Q output
5Q	15	0	5Q output
4Q	16	0	4Q output
3Q	17	0	3Q output
2Q	18	0	2Q output
1Q	19	0	1Q output
V _{CC}	20	_	Power pin
Thermal F	Pad ⁽²⁾	_	The thermal pad can be connect to GND or left floating. Do not connect to any other signal or supply.

⁽¹⁾ I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.

⁽²⁾ For RKS package only.



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	+ 7	V
V _I ²	Input voltage range		-0.5	V _{CC} + 0.5	V
V _O ²	Output voltage range		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	$(V_I < 0 \text{ or } V_I > V_{CC})$		±20	mA
I _{OK}	Output clamp current	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
Io	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$		±50	mA
	Continuous current through, V _{CC} or GN	ND .		±200	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)¹

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2	6	V
		V _{CC} = 3 V	2.1		
V_{IH}	High-level input voltage	V _{CC} = 4.5 V	3.15		V
		V _{CC} = 5.5 V	3.85		
		V _{CC} = 3 V		0.9	
V_{IL}	Low-level input voltage	V _{CC} = 4.5 V		1.35	V
		V _{CC} = 5.5 V		1.65	
VI	Input voltage		0	V _{CC}	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 3 V		-12	
I _{OH}	High-level output current	V _{CC} = 4.5 V		-24	mA
		V _{CC} = 5.5 V		-24	
		V _{CC} = 3 V		12	
I _{OL}	Low-level output current	V _{CC} = 4.5 V		24	mA
		V _{CC} = 5.5 V		24	
Δt/Δν	Input transition rise or fall rate			8	ns/V
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND for proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



5.3 Thermal Information

			SN74AC573						
	THERMAL METRIC		DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	RKS (VQFN)	UNIT	
		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾	101.2	70	69	60	126.2	68	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST OF	TEST CONDITIONS		TA	= 25°C		SN74AC	573	LIMIT
PARAMETER	IESI CO	SNOTTIONS	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
			3 V	2.9			2.9		
	I _{OH} = -50 μA		4.5 V	4.4			4.4		
				5.4			5.4		
V _{OH}	I _{OH} = −12 mA	3 V	2.58			2.48		V	
	24 mA		4.5 V	3.94			3.8		
	I _{OH} = −24 mA		5.5 V	4.94			4.8		
	$I_{OH} = -75 \text{ mA}^{(1)}$		5.5 V				3.85		
	I _{OL} = 50 μA		3 V			0.1		0.1	
			4.5 V			0.1		0.1	
			5.5 V			0.1		0.1	
V _{OL}	I _{OL} = 12 mA		3 V			0.36		0.44	V
	1 = 24 mA		4.5 V			0.36	-	0.44	
	I _{OL} = 24 mA		5.5 V			0.36	-	0.44	
	I _{OL} = 75 mA		5.5 V					1.65	
Iı	V _I = V _{CC} or GND		5.5 V			±0.1		±1	μA
I _{OZ}	V _O = V _{CC} or GND		5.5 V			±0.25		±2.5	μA
I _{CC}	$V_I = V_{CC}$ or GND,	I _O = 0	5.5 V			4		40	μΑ
C _i	V _I = V _{CC} or GND		5 V		5				pF

⁽¹⁾ Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

5.5 Timing Requirements, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

		T _A = 25°C		SN74AC	UNIT	
		MIN	MAX	MIN	MAX	UNIT
t _w	Pulse duration, LE high	6		7		ns
t _{su}	Setup time, data before LE↓	3.5		4		ns
t _h	Hold time, data after LE↓	2		2		ns

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5.6 Timing Requirements, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

		T _A = 25°C		SN74A	C573	UNIT
		MIN	MAX	MIN	MAX	ONIT
t _w	Pulse duration, LE high	4		5		ns
t _{su}	Setup time, data before LE↓	3		3.5		ns
t _h	Hold time, data after LE↓	2		2		ns

5.7 Switching Characteristics, $V_{CC} = 3 V \pm 0.3 V$

over recommended operating free-air temperature range, V_{CC} = 3 V \pm 0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	EDOM (INDUT)	TO (OUTPUT)	T _A = 2	5°C	SN74AC573		UNIT
PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	MAX	MIN	MAX	UNII
t _{PLH}	D	0	2.5	13	2	15	no
t _{PHL}		Q	2.5	12	2	14	ns
t _{PLH}	1.5	Q	2.5	13	2	15	no
t _{PHL}	LE	Q	2.5	12	2	14	ns
t _{PZH}	ŌĒ	Q	2.5	11	2	12	no
t _{PZL}	OE	Q	2.5	11	2	12.5	ns
t _{PHZ}	ŌĒ	Q	2.5	12.5	2	13.5	ne
t _{PLZ}	OE	Q	2.5	9.5	2	10.5	ns

5.8 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	EDOM (INDUT)	TO (OUTDUT)	T _A = 25°	°C	SN74AC573		UNIT
PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	MAX	MIN	MAX	UNII
t _{PLH}	D	Q	2.5	10	2	11.5	
t _{PHL}	D	Q	2.5	9.5	2	11	ns
t _{PLH}	LE	0	2.5	9.5	2	11	
t _{PHL}	_	Q	2.5	8.5	2	10	ns
t _{PZH}	ŌĒ	Q	2.5	9	2	10	
t _{PZL}	- OE	Q	2.5	8.5	2	9.5	ns
t _{PHZ}	- ŌĒ	0	2.5	11	2	12	
t _{PLZ}	⊣ UE	Q	2.5	8	2	9	ns

5.9 Operating Characteristics

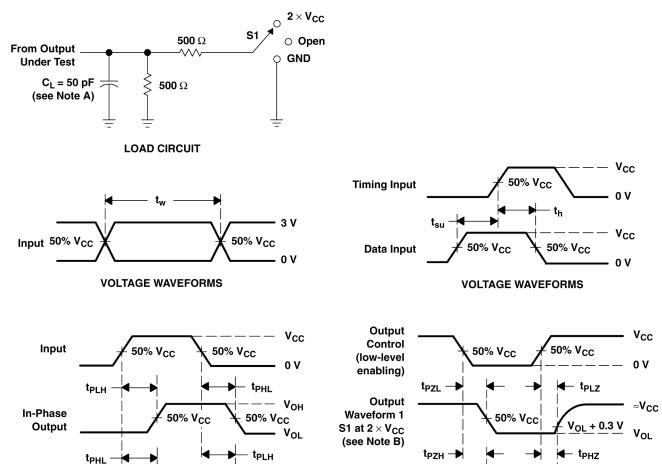
 V_{CC} = 5 V, T_A = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	25	pF

Product Folder Links: SN74AC573



6 Parameter Measurement Information



VOLTAGE WAVEFORMS

VOLTAGE WAVEFORMS

50% V_{CC}

V_{OH} – 0.3 V

≈0 V

A. C_L includes probe and jig capacitance.

Out-of-Phase

Output

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

Output

Waveform 2

S1 at Open

(see Note B)

C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq 2.5$ ns, $t_f \leq 2.5$ ns.

 \mathbf{v}_{OH}

 V_{OL}

D. The outputs are measured one at a time with one input transition per measurement.

50% V_{CC}

Figure 6-1. Load Circuit and Voltage Waveforms

Table 6-1.

TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	2 × V _{CC}
t _{PHZ} /t _{PZH}	Open

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7 Detailed Description

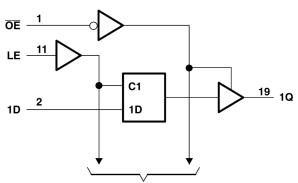
7.1 Overview

The eight latches are D-type transparent latches. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D Inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines in a bus-organized system without need for interface or pullup components.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

7.2 Functional Block Diagram



To Seven Other Channels

Figure 7-1. Logic Diagram (Positive Logic)

7.3 Device Functional Modes

Table 7-1. Function Table (Each Latch)

I	NPUTS ⁽¹⁾		OUTPUT ⁽²⁾ Q
OE	LE	D	OUIFUI() Q
L	Н	Н	Н
L	Н	L	L
L	L	Х	Q_0
Н	Х	Х	Z

- (1) H = High voltage level, L = Low voltage level, X = High or low voltage level
- (2) H = Driving high, L = Driving low, Q₀ = Driving previous high or low state, Z = High impedance



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the Section 5.2 table. The total current through Ground or V_{CC} must not exceed ± 70 mA as per Section 5.1 table.

Each V_{CC} pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends 0.1- μ F capacitor; if there are multiple V_{CC} pins, then TI recommends 0.01- μ F or 0.022- μ F capacitor for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1- μ F and 1- μ F capacitor are commonly used in parallel. The bypass capacitor must be installed as close to the power pin as possible for best results.

8.2 Layout

8.2.1 Layout Guidelines

When using multiple-bit logic devices, inputs must never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input and the gate are used, or only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Layout Diagram specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, they are tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it disables the output section of the part when asserted. This does not disable the input section of the I/Os, so they cannot float when disabled.

8.2.2 Layout Example

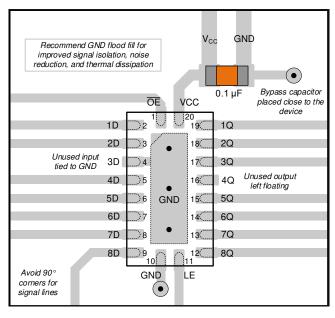


Figure 8-1. Layout example of the SN74AC573

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9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on Notifications to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (November 2023) to Revision H (February 2024)	Page
 Added body size to <i>Package Information</i> table Updated RθJA values: DW = 58 to 101.2, PW = 83 to 126.2, all values in °C/W 	
Added Application and Implementation section	
Changes from Revision F (June 2023) to Revision G (November 2023)	Page
Updated the Package Information table to include package lead size. Added the RKS package information	
, laded the , i.e. package mematicin	

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74AC573



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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AC573DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573DBRG4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85	AC573	
SN74AC573DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573	Samples
SN74AC573DWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573N	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74AC573N	Samples
SN74AC573NSR	ACTIVE	SOP	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573PW	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 85	AC573	
SN74AC573PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573	Samples
SN74AC573PWRE4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573RKSR	ACTIVE	VQFN	RKS	20	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

PACKAGE OPTION ADDENDUM

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- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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OTHER QUALIFIED VERSIONS OF SN74AC573:

Automotive: SN74AC573-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AC573DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AC573DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AC573DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74AC573NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AC573PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AC573PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AC573RKSR	VQFN	RKS	20	3000	180.0	12.4	2.8	4.8	1.2	4.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AC573DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74AC573DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AC573DWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74AC573NSR	SOP	NS	20	2000	367.0	367.0	45.0
SN74AC573PWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74AC573PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74AC573RKSR	VQFN	RKS	20	3000	210.0	185.0	35.0

PACKAGE MATERIALS INFORMATION

www.ti.com 7-Dec-2024

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74AC573N	N	PDIP	20	20	506	13.97	11230	4.32





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



2.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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